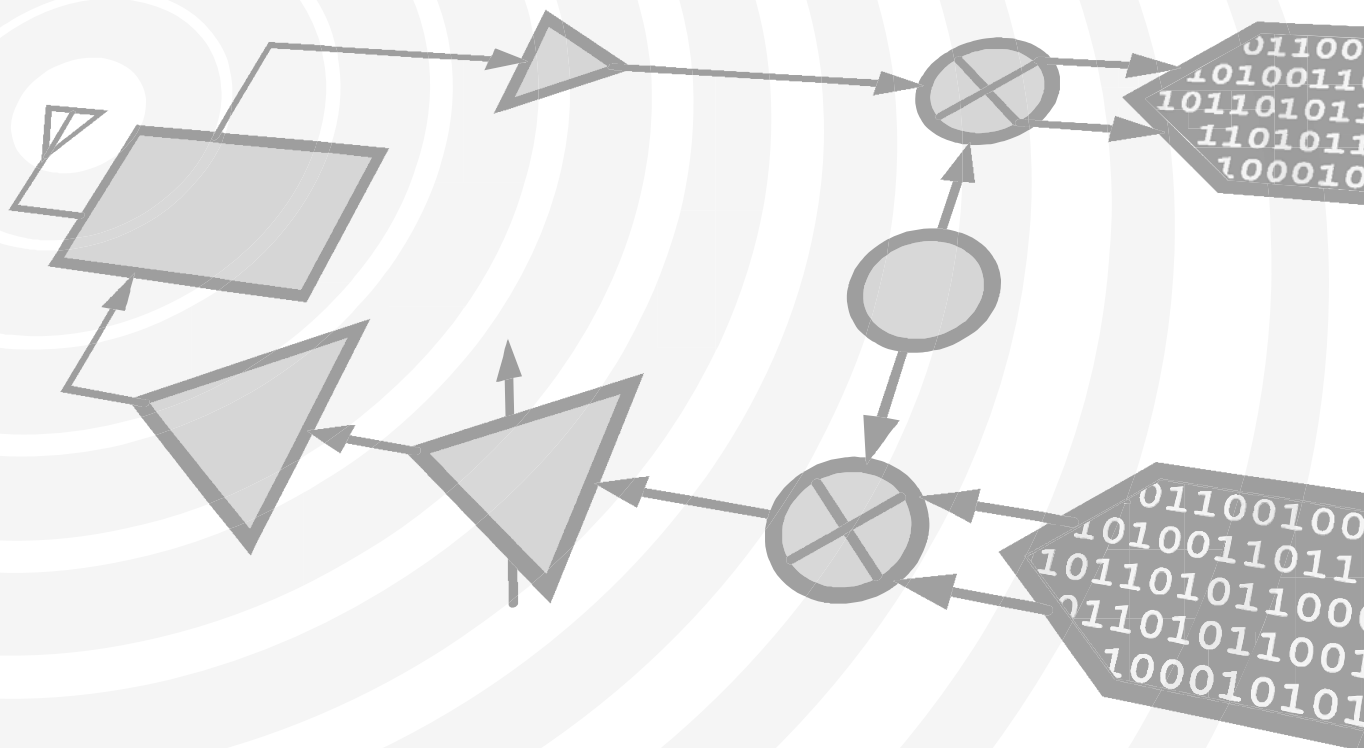




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION

v02.0813



HMC740ST89E

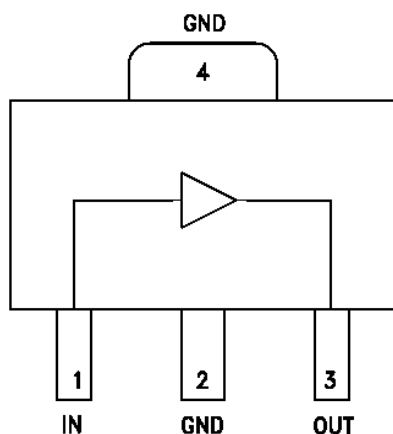
InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

Typical Applications

The HMC740ST89E is ideal for:

- Cellular/3G & WiMAX/4G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment
- IF & RF Applications

Functional Diagram



Features

- P1dB Output Power: +18 dBm
- Gain: 15 dB
- Output IP3: +40 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +5V
- Industry Standard SOT89 Package
- Robust 1000V ESD, Class 1C
- Stable Current Over Temperature
- Active Bias Network

General Description

The HMC740ST89E is an InGaP Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifier covering 0.05 to 3 GHz. Packaged in an industry standard SOT89, the amplifier can be used as a cascadable 50 Ohm RF or IF gain stage as well as a PA or LO driver with up to +18 dBm output power. The HMC740ST89E offers 15 dB of gain with a +40 dBm output IP3 at 100 MHz, and can operate directly from a +5V supply. The HMC740ST89E exhibits excellent gain and output power stability over temperature, while requiring a minimal number of external bias components.

Electrical Specifications, $V_{cc} = 5V$, $T_A = +25^\circ C$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		0.05 - 1			0.05 - 3		GHz
Gain	12	15		11	15		dB
Gain Flatness		± 0.1			± 0.7		dB
Gain Variation over Temperature		0.003	0.006		0.003	0.006	dB/ $^\circ C$
Input Return Loss		18			15		dB
Output Return Loss		18			18		dB
Reverse Isolation		20			21		dB
Output Power for 1 dB Compression (P1dB)	15.5	18		14.5	17		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)		38			32		dBm
Noise Figure		3.5			3.5		dB
Supply Current (Icq)		88			88		mA

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

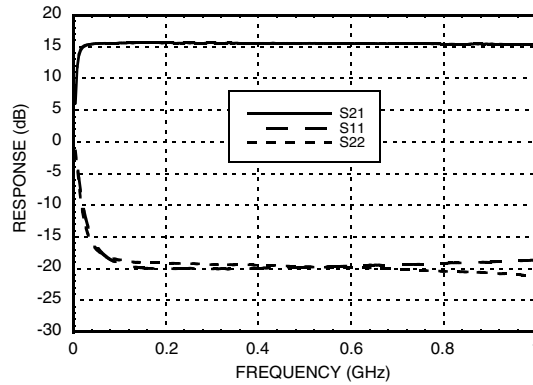
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

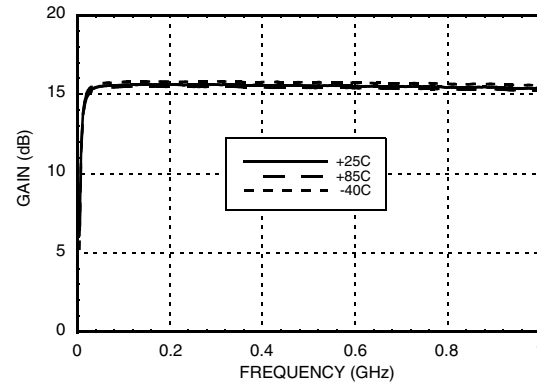
InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

IF Band Performance

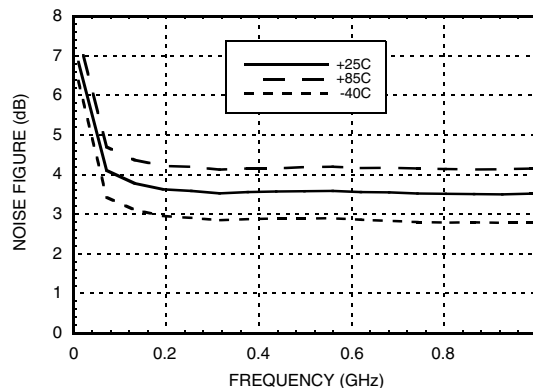
Gain & Return Loss



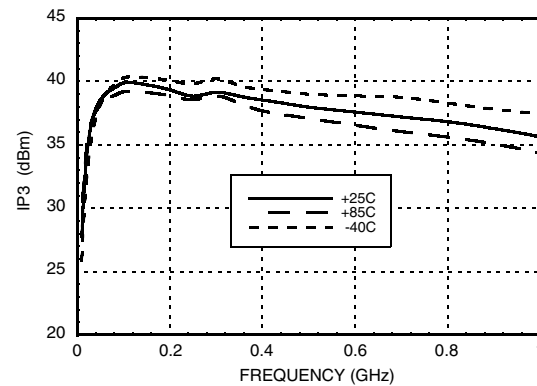
Gain vs. Temperature



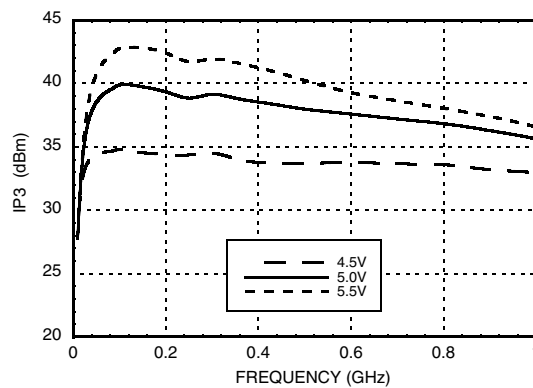
Noise Figure vs. Temperature



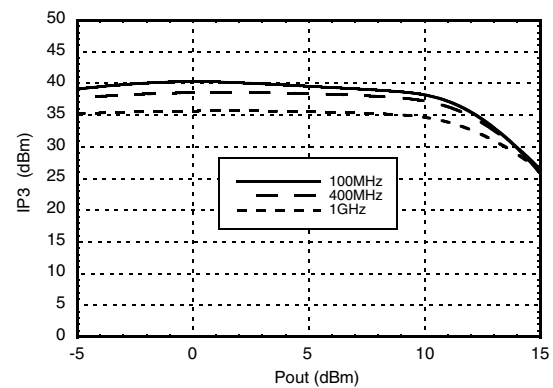
Output IP3 vs. Temperature



Output IP3 vs. Vcc



Output IP3 vs. Output Power





MICROWAVE CORPORATION v02.0813

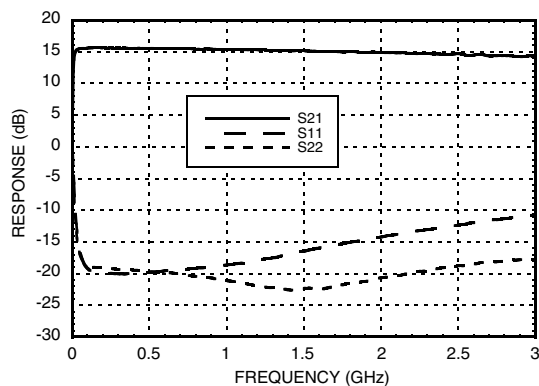


HMC740ST89E

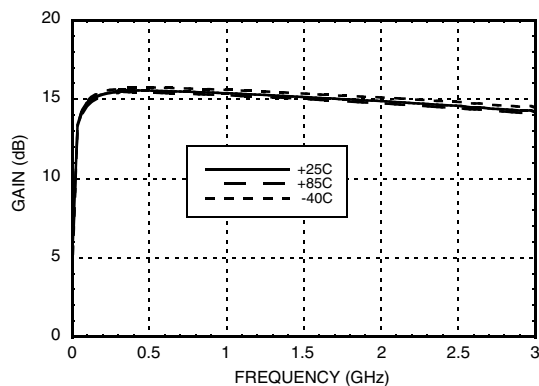
**InGaP HBT ACTIVE BIAS
MMIC AMPLIFIER, 0.05 – 3 GHz**

Broadband Performance

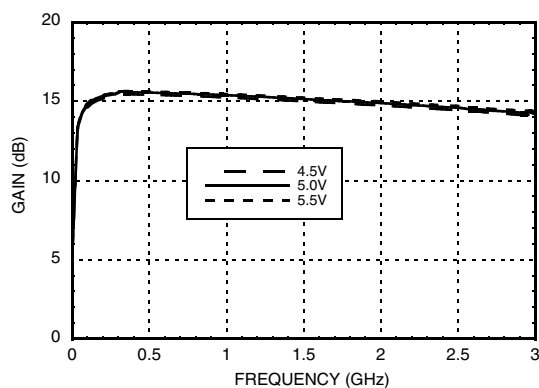
Gain & Return Loss



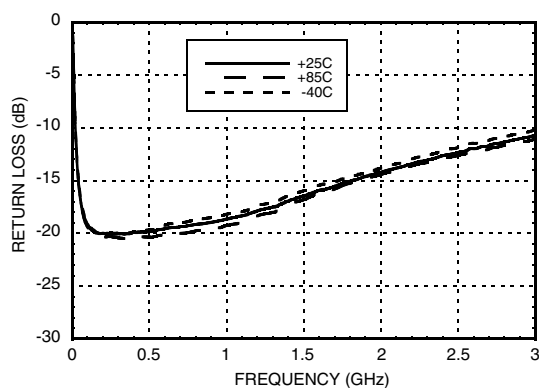
Gain vs. Temperature



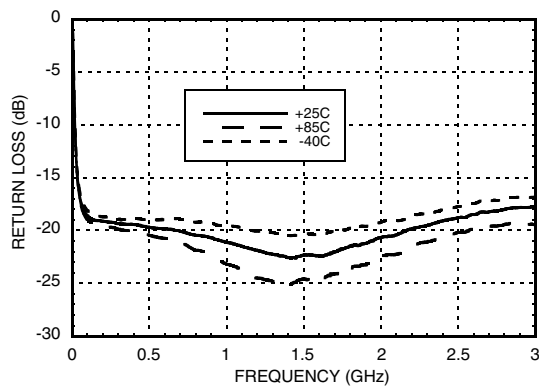
Gain vs. Vcc



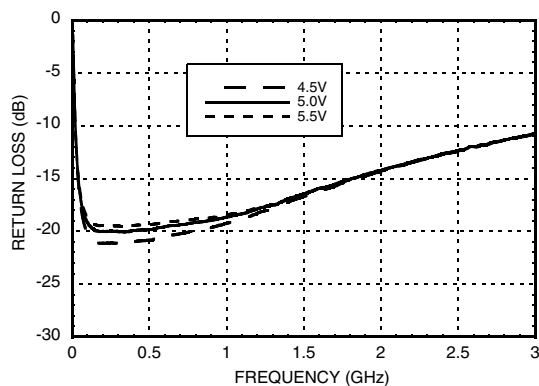
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature

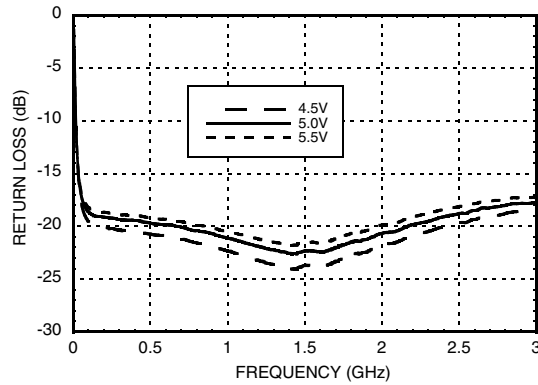


Input Return Loss vs. Vcc

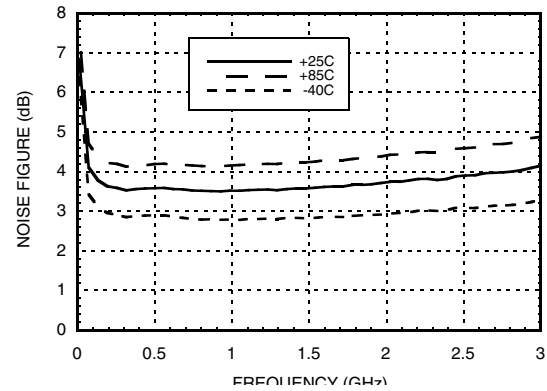


InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

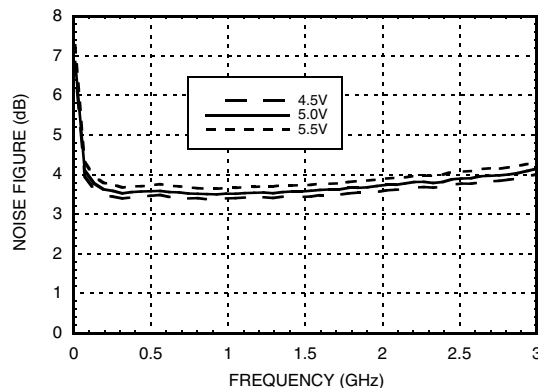
Output Return Loss vs. Vcc



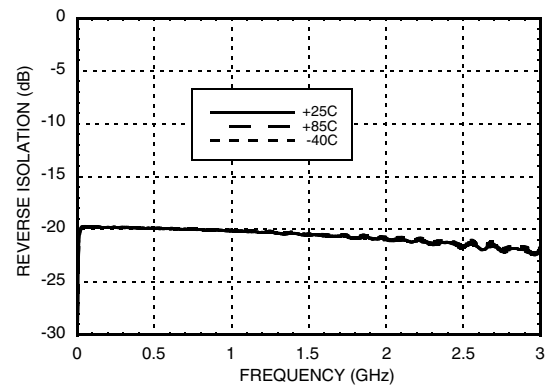
Noise Figure vs. Temperature



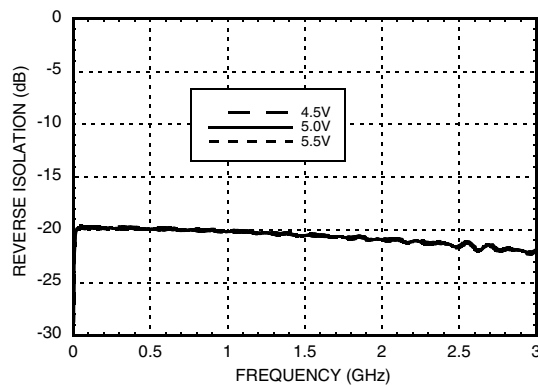
Noise Figure vs. Vcc



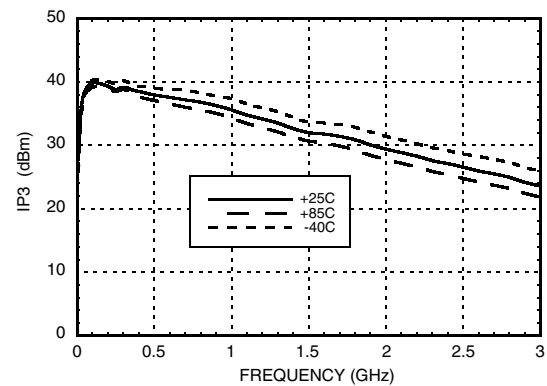
Reverse Isolation vs. Temperature



Reverse Isolation vs. Vcc

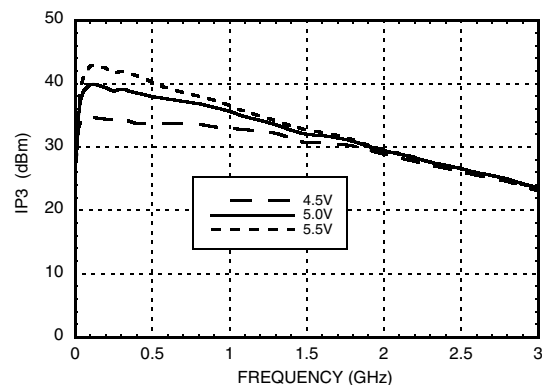


Output IP3 vs. Temperature

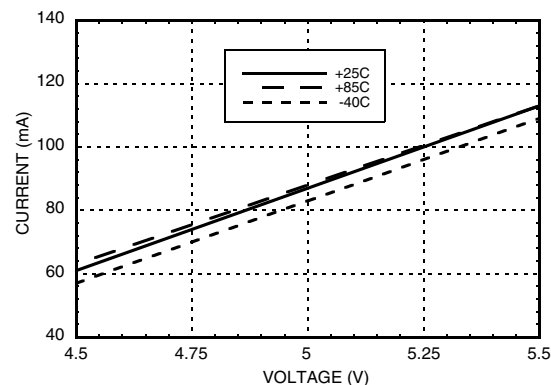


InGaP HBT ACTIVE BIAS MMIC AMPLIFIER, 0.05 – 3 GHz

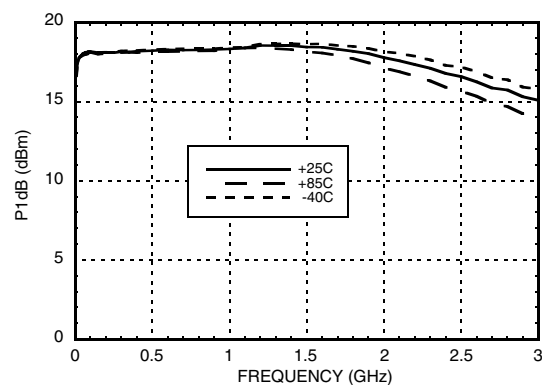
Output IP3 vs. Vcc



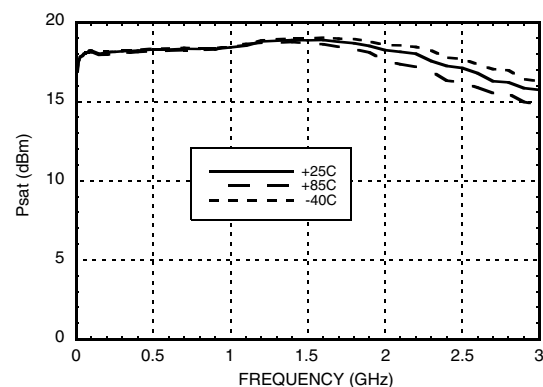
Current vs. Temperature



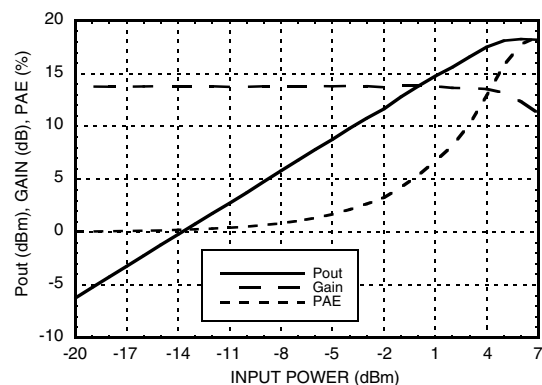
P1dB vs. Temperature



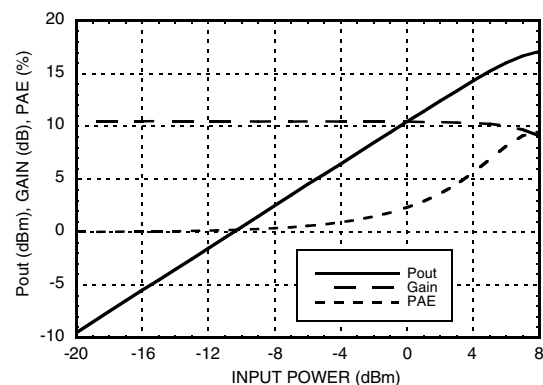
Psat vs. Temperature



Power Compression @ 500 MHz



Power Compression @ 2 GHz



Absolute Maximum Ratings

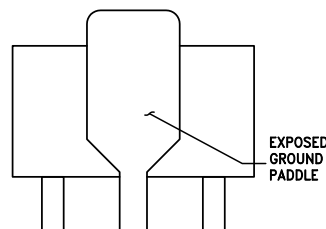
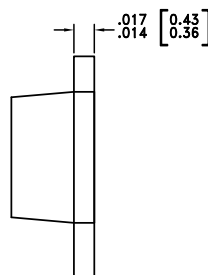
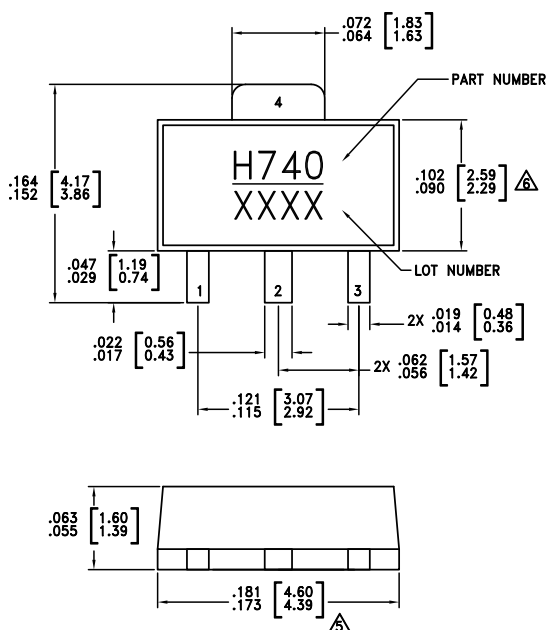
Collector Bias Voltage (Vcc)	+5.5 Vdc
RF Input Power (RFIN)	+15 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 10.23 mW/°C above 85 °C)	0.66 W
Thermal Resistance (junction to lead)	97.78 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HMB)	Class 1C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

8

Outline Drawing



NOTES:

- PACKAGE BODY MATERIAL:
MOLDING COMPOUND MP-180S OR EQUIVALENT.
- LEAD MATERIAL: Cu w/ Ag SPOT PLATING.
- LEAD PLATING: 100% MATTE TIN.
- DIMENSIONS ARE IN INCHES (MILLIMETERS)
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[1]
HMC740ST89E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H740 XXXX

[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C



MICROWAVE CORPORATION v02.0813



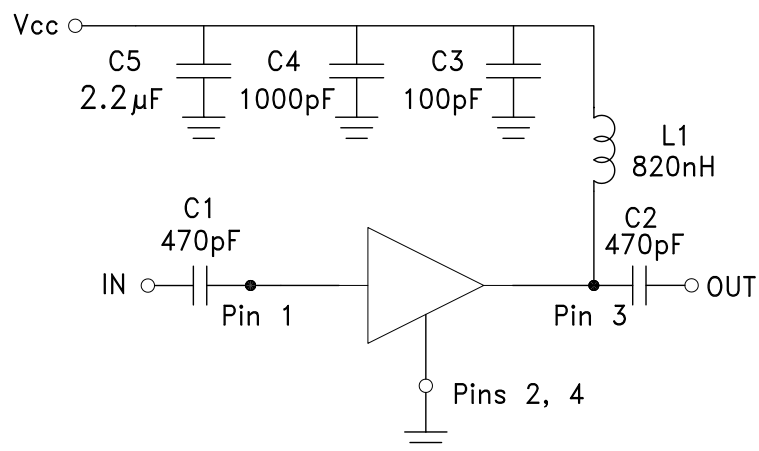
HMC740ST89E

**InGaP HBT ACTIVE BIAS
MMIC AMPLIFIER, 0.05 – 3 GHz**

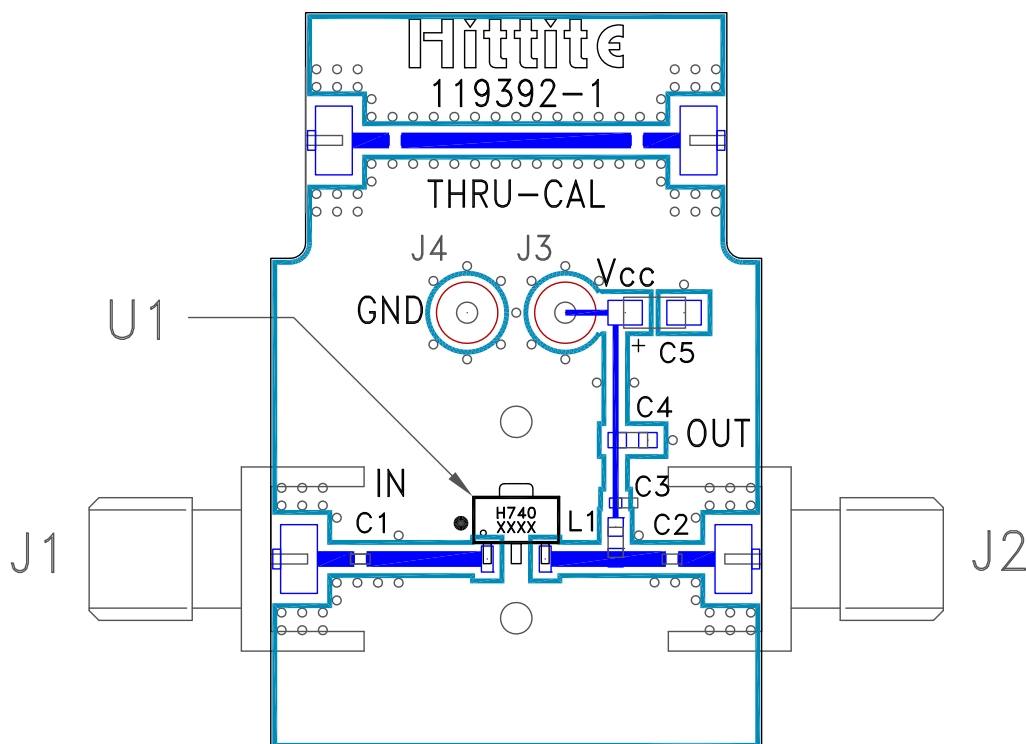
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	IN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	OUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins and package bottom must be connected to RF/DC ground.	

Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 124390 ^[1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pin
C1, C2	470 pF Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 μ F Capacitor Tantalum
L1	820 nH Inductor, 0603 Pkg.
U1	HMC740ST89E
PCB [2]	119392 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: FR4

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.



ООО «НИОКРсистемс» - это оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов. Реализуемая нашей компанией продукция насчитывает более полумиллиона наименований.

Благодаря этому наша компания предлагает к поставке практически не ограниченный ассортимент компонентов как оптовыми, мелкооптовыми партиями, так и в розницу.

Благодаря развитой сети поставщиков, помогаем в поиске и приобретении экзотичных или снятых с производства компонентов.

Наша компания это:

- Гарантия качества поставляемой продукции
- Широкий ассортимент
- Минимальные сроки поставок
- Техническая поддержка
- Подбор комплектации
- Индивидуальный подход
- Гибкое ценообразование
- Работаем по 275 ФЗ